



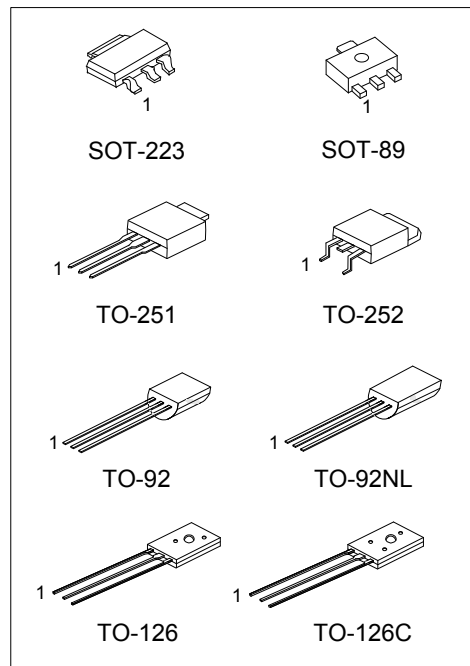
2SD669/A

NPN SILICON TRANSISTOR

BIPOLAR POWER GENERAL PURPOSE TRANSISTOR

APPLICATIONS

* Low frequency power amplifier complementary pair with UTC 2SB649/A



Lead-free: 2SD669L/2SD669AL
Halogen-free: 2SD669G/2SD669AG

ORDERING INFORMATION

Ordering Number			Package	Pin Assignment			Packing
Normal	Lead Free	Halogen Free		1	2	3	
2SD669x-x-AA3-R	2SD669xL-x-AA3-R	2SD669xG-x-AA3-R	SOT-223	B	C	E	Tape Reel
2SD669x-x-AB3-R	2SD669xL-x-AB3-R	2SD669xG-x-AB3-R	SOT-89	B	C	E	Tape Reel
2SD669x-x-T60-K	2SD669xL-x-T60-K	2SD669xG-x-T60-K	TO-126	E	C	B	Bulk
2SD669x-x-T6C-K	2SD669xL-x-T6C-K	2SD669xG-x-T6C-K	TO-126C	E	C	B	Bulk
2SD669x-x-T92-B	2SD669xL-x-T92-B	2SD669xG-x-T92-B	TO-92	E	C	B	Tape Box
2SD669x-x-T92-K	2SD669xL-x-T92-K	2SD669xG-x-T92-K	TO-92	E	C	B	Bulk
2SD669x-x-T9N-B	2SD669xL-x-T9N-B	2SD669xG-x-T9N-B	TO-92NL	E	C	B	Tape Box
2SD669x-x-T9N-K	2SD669xL-x-T9N-K	2SD669xG-x-T9N-K	TO-92NL	E	C	B	Bulk
2SD669x-x-TM3-T	2SD669xL-x-TM3-T	2SD669xG-x-TM3-T	TO-251	B	C	E	Tube
2SD669x-x-TN3-R	2SD669xL-x-TN3-R	2SD669xG-x-TN3-R	TO-252	B	C	E	Tape Reel

<p>2SD669xL-x-AB3-R</p> <p>(1)Packing Type (2)Package Type (3)Rank (4)Lead Plating (5) Collector-Emitter Voltage</p>	<p>(1) B: Tape Box, K: Bulk, R: Tape Reel (2) AA3: SOT-223, AB3: SOT-89, T60: TO-126, T6C: TO-126C, TM3: TO-251, TN3: TO-252, T92:TO-92, T9N: TO-92NL (3) x: refer to Classification of h_{FE1} (4) G: Halogen Free, L: Lead Free, Blank: Pb/Sn (5) A: 160V, Blank: 120V</p>
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■ ABSOLUTE MAXIMUM RATING (Ta=25°C unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V _{CBO}	180	V
Collector-Emitter Voltage	2SD669	V _{CEO}	120	V
	2SD669A		160	
Emitter-Base Voltage		V _{EBO}	5	V
Collector Current		I _C	1.5	A
Collector Peak Current		I _{C(PEAK)}	3	A
Collector Dissipation	SOT-223	P _D	0.5	W
	SOT-89		0.5	W
	TO-126/TO-126C		1	W
	TO-92/TO-92NL		0.6	W
	TO-251		1	W
	TO-252		2	W
Junction Temperature		T _J	150	°C
Storage Temperature		T _{STG}	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

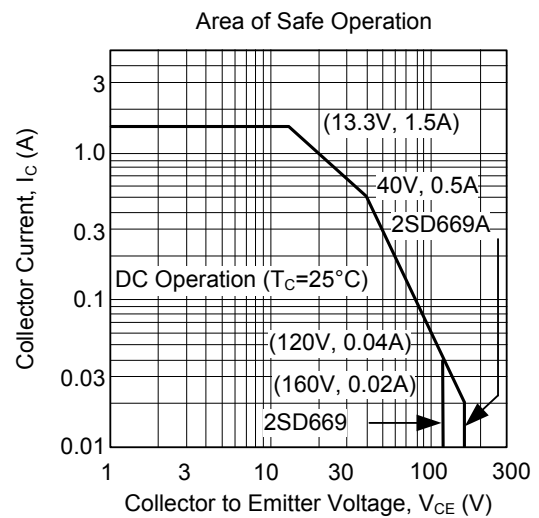
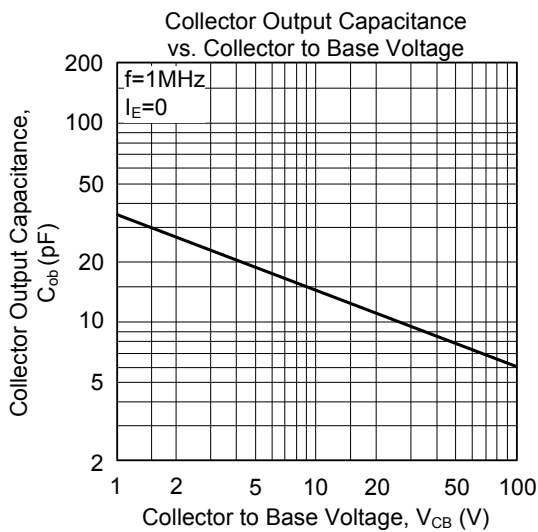
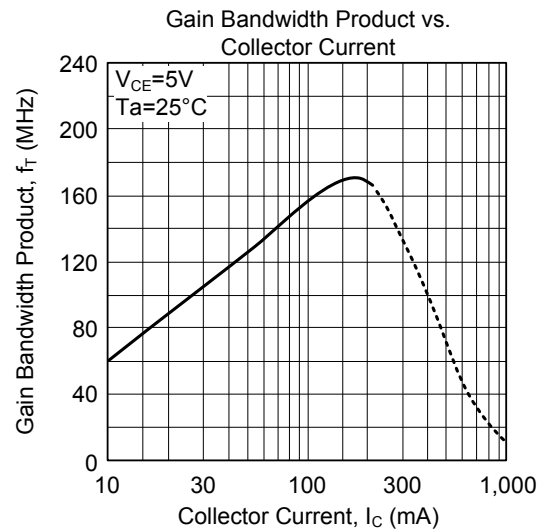
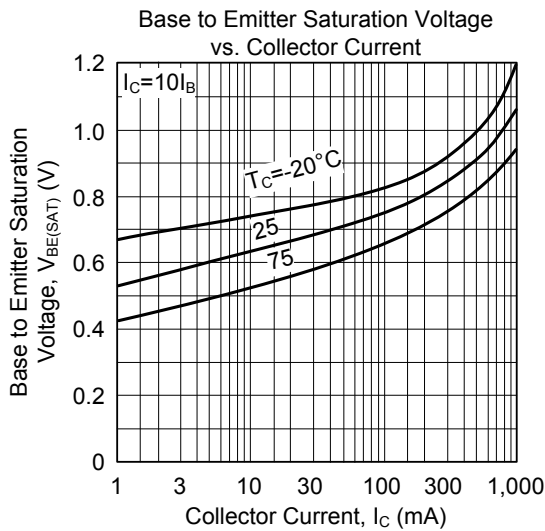
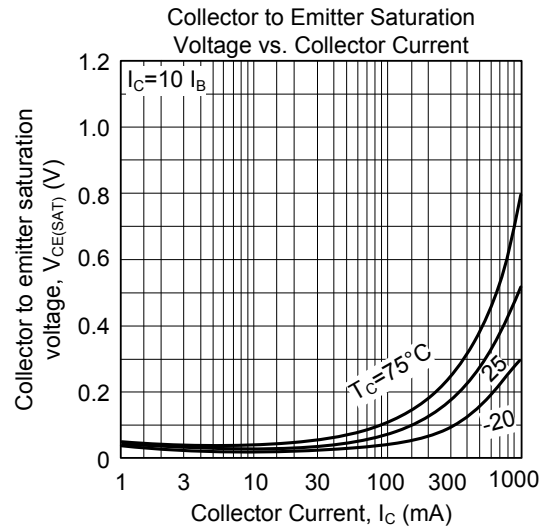
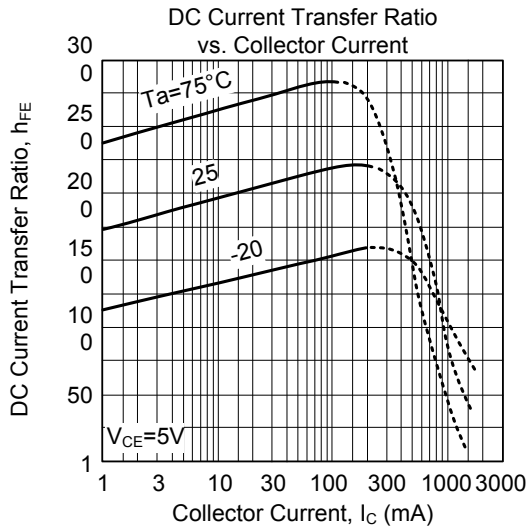
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector to Base Breakdown Voltage	BV _{CBO}	I _C =1mA, I _E =0	180			V
Collector to Emitter Breakdown Voltage	BV _{CEO}	I _C =10mA, R _{BE} =∞	120			V
			160			
Emitter to Base Breakdown Voltage	BV _{EBO}	I _E =1mA, I _C =0	5			V
Collector Cut-off Current	I _{CBO}	V _{CB} =160V, I _E =0			10	μA
DC Current Gain	h _{FE1}	V _{CE} =5V, I _C =150mA (Note)	60		320	
	h _{FE2}	V _{CE} =5V, I _C =500mA (Note)	30			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =600mA, I _B =50mA (Note)			1	V
Base-Emitter Voltage	V _{BE}	V _{CE} =5V, I _C =150mA (Note)			1.5	V
Current Gain Bandwidth Product	f _T	V _{CE} =5V, I _C =150mA (Note)		140		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, I _E =0, f=1MHz		14		pF

Note: Pulse test.

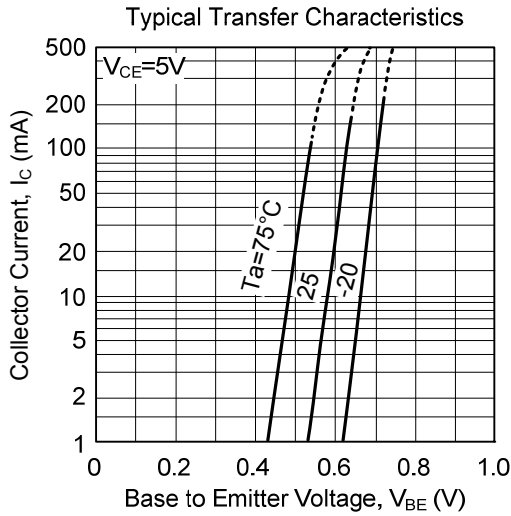
■ CLASSIFICATION OF h_{FE1}

RANK	B	C	D
RANGE	60-120	100-200	160-320

TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS(Cont.)



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